

74HCT00

QUADRUPLE 2-INPUT NAND GATES

Description

The 74HCT00 provides provides four independent 2-input NAND gates with standard push-pull outputs. The device is designed for operation with a power supply range of 4.5V to 5.5V.

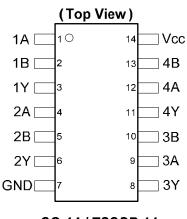
The gates perform the Boolean function:

 $Y = \overline{A \bullet B} \text{ or } Y = \overline{A} + \overline{B}$

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Pin Compatible with Low Power Schottky (LSTTL)
- Inputs Are TTL Voltage Level Compatible
- Sinks or sources 4mA at Vcc = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
 - Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

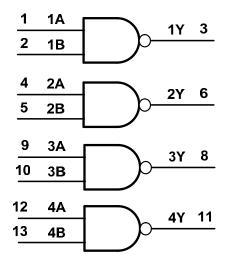
See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Function	
1	1A	Data Input	
2	1B	Data Input	
3	1Y	Data Output	
4	2A	Data Input	
5	2B	Data Input	
6	2Y	Data Output	
7	GND	Ground	
8	3Y	Data Output	
9	3A	Data Input	
10	3B	Data Input	
11	4Y	Data Output	
12	4A	Data Input	
13	4B	Data Input	
14	Vcc	Supply Voltage	

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$	±20	mA
lok	Output Clamp Current $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	±20	mA
lo	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
Icc	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Input Voltage cannot exceed $V_{\mbox{\tiny CC}}$ to the extent the Maximum clamp current is exceeded.

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage		4.5	5.5	V
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage		0	V _{CC}	V
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 4.5V to 5.5V		500	ns/V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol Parameter		Test Conditions	v	T _A = -40°C to +85°C		T _A = -40°C	to +125°C	Unit
Symbol	mbol Parameter Test Conditions V _{CC}		Min	Max	Min	Max	Unit	
V _{IH}	High-level Input Voltage		4.5V to 5.5V	2.0		2.0		V
VIL	Low-level Input Voltage		4.5V to 5.5V		0.8		0.8	V
, High-level Output		I _{OH} = -20µА	4.5V	4.4		4.4		v
V _{OH} Voltage	I _{OH} = -4mA	4.5V	3.84		3.70		v	
M	Low-level Output	I _{OL} = 20μA	4.5V		0.1		0.1	v
V _{OL}	Voltage	I _{OL} = 4.0mA	4.5V		0.33		0.4	v
h	Input Current	VI =GND to 6.0V	6.0V		± 1		± 1	μA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	6.0V		20		40	μA
ΔI_{CC}	Additional Supply Current	One Input at V_{CC} -2.1V Other pins at V_{CC} or GND	4.5V to 5.5V		675		735	μA



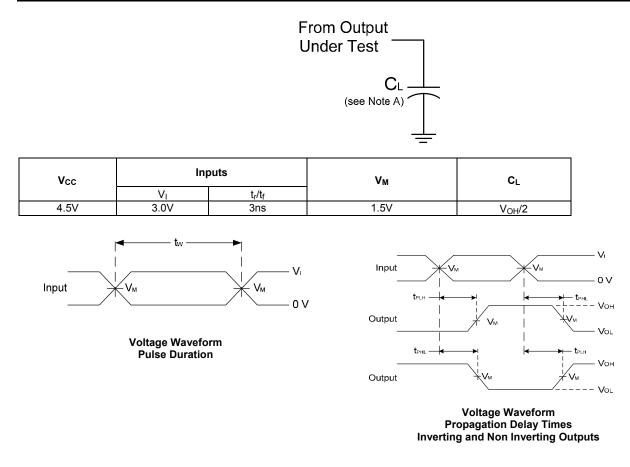
Switching Characteristics

Symbol	Parameter	Test	Vcc		Γ _A = +25°0	;	-40°C to +85°C	-40°C to +125°C	Unit
Cymbol	i arameter	Conditions	¥CC	Min	Тур	Max	Max	Max	Onic
t _{PD}	Propagation Delay A _N to Y _N	Figure 1 C _L = 50pF	4.5V	_	12	22	24	29	ns
t _t	Transition Time	Figure 1 C _L = 50pF	4.5V	_	7	22	22	29	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 5.5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	12	pF
CI	Input Capacitance	$V_{I} = V_{CC} - or GND$	3.5	pF

Parameter Measurement Information



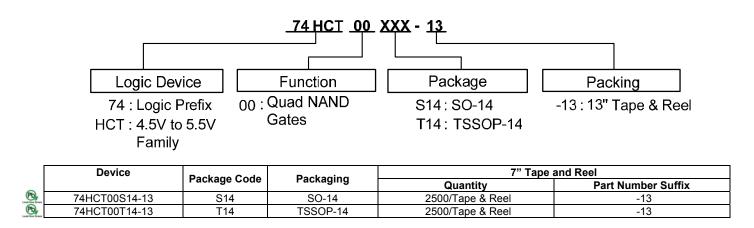
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as $t_{\mathsf{PD.}}$

Figure 1 Load Circuit and Voltage Waveforms

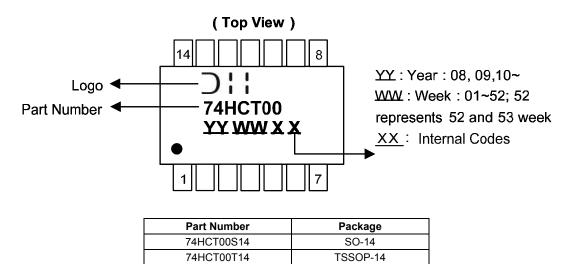


Ordering Information



Marking Information

(1) SO-14, TSSOP-14

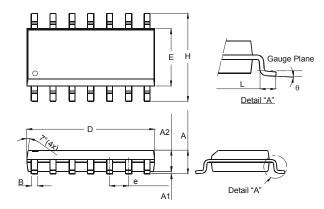




Package Outline Dimensions (All dimensions in mm.)

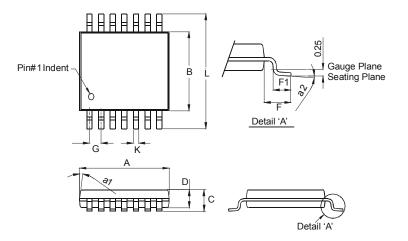
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14						
Dim	Min	Max					
Α	1.47	1.73					
A1	0.10	0.25					
A2	1.45	Тур					
В	0.33	0.51					
D	8.53	8.74					
Е	3.80	3.99					
е	1.27	Тур					
Н	5.80	6.20					
L	0.38	1.27					
θ	0°	8°					
All Di	mensions	s in mm					

Package Type: TSSOP-14



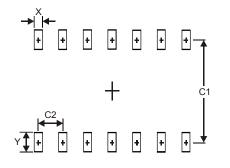
	TSSOP-14					
Dim	Min Max					
a1	7° (4X)				
a2	0°	8°				
Α	4.9	5.10				
В	4.30 4.50					
C		1.2				
D	0.8	1.05				
F	1.00 Typ					
F1	0.45 0.75					
G	0.65	Тур				
Κ	0.19 0.30					
L	L 6.40 Typ					
All Dir	nension	s in mm				



Suggested Pad Layout

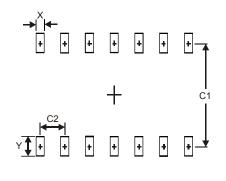
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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